	•	••			Docket Number (Optional) BUR9200300		oplication Number	604	116
w.	INFO	RMATION DISCLOSUR			Applicant(s) Anderson et al.		/		
	10	IPE	,,		Piling Date		roup Art Unit	2823	
	-	217003		U.S. PA	TENT DOCUMENTS	/03		~~	
*EXAMINER INITIAL	1	7100	T	1	NAME	CLASS	SUBCLASS	FILING	DATE
INITIAL	V	DOCUMENT NUMBER	DATE	-	NAME	CLASS	SUBCEASS	IF APPRO	PRIATE
	ļ								
•									
	-						 		
	 	· · · · · · · · · · · · · · · · · · ·						<u> </u>	
	ļ			 				ļ	
							, in the second		
·····	<u></u>			FOREIC	SN PATENT DOCUMEN	TS	i .	<u> </u>	
			COUNTRY CLASS		SUBCLASS	Trans	lation		
01/	REF	DOCUMENT NUMBER						YES	NO
289		EP0721221A2	7/1996	EP					
					· · · · · · · · · · · · · · · · · · ·				
				1					
	L	<u> </u>	4,,,=1,4	OTHER	DOCUMENTS (Include	ling Author, Title, D	ate, Pertinent Pa	iges, Etc.)	
		Doo, V.Y., "Method of	Making Submic		el MOSFET," IBM Te			•	,
12		December 1301, pp. 34							
2	1							3 at	
									
EXAMINE	R	Joannie A. Har			DATE CONSIDERED	May 1	9, 200	S	
EXAMINE	R: Initi	if citation considered, whether	r or not citation is	in conforma	nce with MPEP Section 60				ance and
not considered. Include copy of this form with next communication to applicant.									

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18
Stylesheet Version v18.0

Title of Invention

METHOD OF FORMING FREESTANDING SEMICONDUCTOR LAYER

Application Number:

10/604,116

Confirmation Number:

First Named Applicant: Brent Anderson
Attorney Docket Number: BUR920030031US1

Search string:

(5723370 or 6492212 or 20020181523).pn.

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
JA	1	5723370	1998-03-03	Ning et al		-	
MY.	2	6492212	2002-12-10	leong, et al			

US Published Applications

Note: Applicant is not required to submit a paper copy of cited US Published Applications

init	Cite.No.	Pub. No.	Date	Applicant	Kind	Class	Subclass
38	1	20020181523	2002-12-05	Pinneo, et al			

Signature

Examiner Name	Date
Joanni A. Garas	May 19, 2505